preliminary

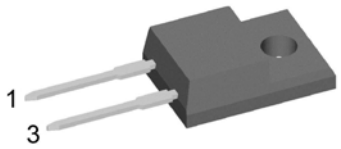
Schottky Diode Gen ²

V_{RRM} = 100V
I_{FAV} = 10A
V_F = 0.71V

High Performance Schottky Diode
Low Loss and Soft Recovery
Single Diode

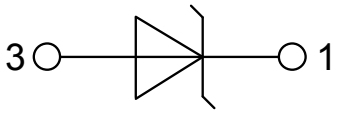
Part number

DSA10I100PM



Backside: isolated

E72873



Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-220FP

- Isolation Voltage: 2500 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

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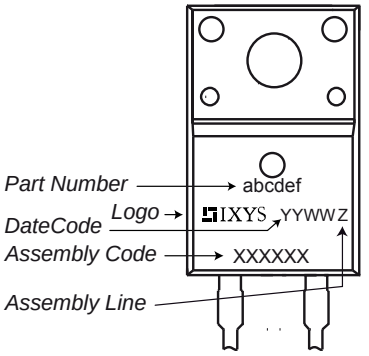
Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	*max. non-repetitive reverse blocking voltage*		T_{VJ} = 25°C			100	V
V_{RRM}	*max. repetitive reverse blocking voltage*		T_{VJ} = 25°C			100	V
I_R	*reverse current, drain current*	V_R = 100 V	T_{VJ} = 25°C			200	µA
		V_R = 100 V	T_{VJ} = 125°C			2	mA
V_F	*forward voltage drop*	I_F = 10 A	T_{VJ} = 25°C			0.89	V
		I_F = 20 A				1.04	V
		I_F = 10 A	T_{VJ} = 125°C			0.71	V
		I_F = 20 A				0.87	V
I_{FAV}	*average forward current*	T_C = 140°C	T_{VJ} = 175°C			10	A
		rectangular d = 0.5					
V_{F0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 175°C			0.45	V
r_F	*slope resistance* }					16.1	mΩ
R_{thJC}	*thermal resistance junction to case*					4.5	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.50		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			35	W
I_{FSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine; V_R = 0 V	T_{VJ} = 45°C			240	A
C_J	*junction capacitance*	V_R = 12 V f = 1 MHz	T_{VJ} = 25°C		96		pF

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preliminary

Package TO-220FP				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
I_{RMS}	*RMS current*	per terminal				35	A
T_{VJ}	*virtual junction temperature*			-55		175	°C
T_{op}	*operation temperature*			-55		150	°C
T_{stg}	*storage temperature*			-55		150	°C
Weight					2		g
M_D	*mounting torque*			0.4		0.6	Nm
F_C	*mounting force with clip*			20		60	N
$d_{Spp/App}$	*creepage distance on surface | striking distance through air*	*terminal to terminal*	3.2	2.7			mm
$d_{Spb/Apb}$		*terminal to backside*	2.5	2.5			mm
V_{ISOL}	*isolation voltage*	t = 1 second	50/60 Hz, RMS; I_{ISOL} ≤ 1 mA	2500			V
		t = 1 minute		2080			V

Product Marking

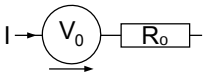


Part number

D = Diode
S = Schottky Diode
A = low VF
10 = Current Rating [A]
I = Single Diode
100 = Reverse Voltage [V]
PM = TO-220ACFP (2)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA10I100PM	DSA10I100PM	Tube	50	503362

Equivalent Circuits for Simulation ** on die level* T_{VJ} = 175 °C

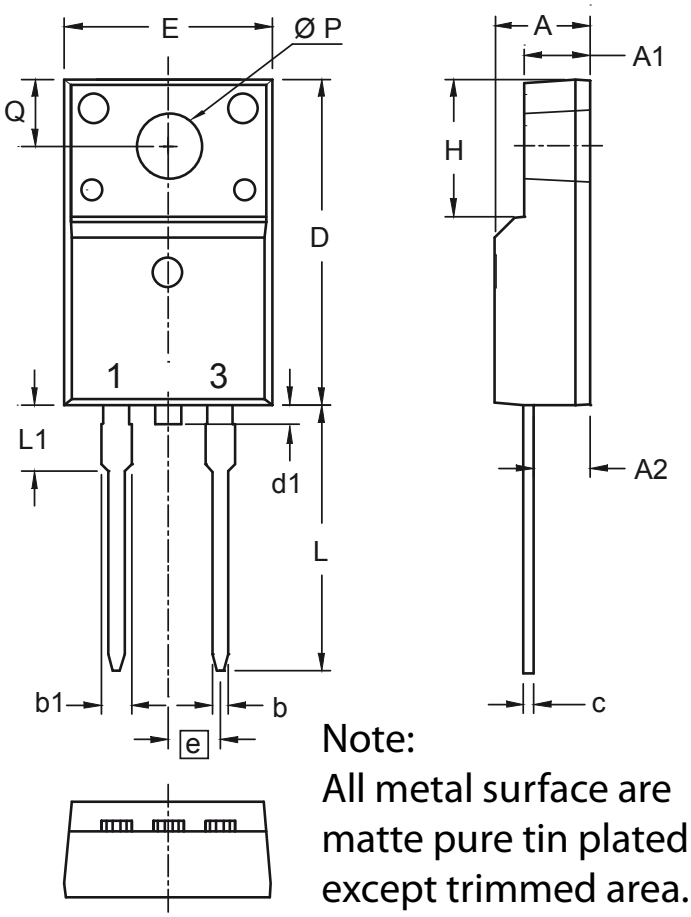


Schottky

$V_{0\,max}$	*threshold voltage*	0.45	V
$R_{0\,max}$	*slope resistance **	12.9	mΩ

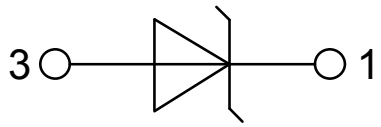
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Outlines TO-220FP



Note:
All metal surface are matte pure tin plated except trimmed area.

Dim.	Millimeters		Inches	
	min	max	min	max
A	4.50	4.90	0.177	0.193
A1	2.34	2.74	0.092	0.108
A2	2.56	2.96	0.101	0.117
b	0.70	0.90	0.028	0.035
b1	1.27	1.47	0.050	0.058
c	0.45	0.60	0.018	0.024
D	15.67	16.07	0.617	0.633
d1	0	1.10	0	0.043
E	9.96	10.36	0.392	0.408
e	2.54 BSC		0.100 BSC	
H	6.48	6.88	0.255	0.271
L	12.68	13.28	0.499	0.523
L1	3.03	3.43	0.119	0.135
Ø P	3.08	3.28	0.121	0.129
Q	3.20	3.40	0.126	0.134



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